Single 2-Input OR Gate

The NL17SZ32 is a single 2-input OR Gate in two tiny footprint packages. The device performs much as LCX multi-gate products in speed and drive. They should be used wherever the need for higher speed and drive are needed.

Features

- Tiny SOT-353 and SOT-553 Packages
- 2.4 ns T_{PD} at 5.0 V (typ)
- Source/Sink 24 mA at 3.0 V
- Over-Voltage Tolerant Inputs
- Pin For Pin with NC7SZ32P5X, TC7SZ32FU and TC7SZ32AFE
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- These Devices are Pb-Free and are RoHS Compliant
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable

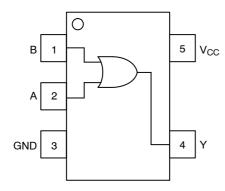


Figure 1. Pinout (Top View)

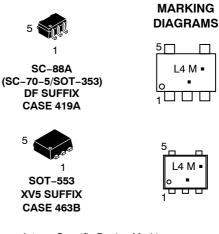


Figure 2. Logic Symbol



ON Semiconductor®

http://onsemi.com



L4 = Specific Device Marking

- M = Date Code*
- = Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT

Pin	Function
1	В
2	А
3	GND
4	Y
5	V _{CC}

FUNCTION TABLE

Ing	Output Y = A + B	
А	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter		Value	Units
V _{CC}	DC Supply Voltage		–0.5 to +7.0	V
V _{IN}	DC Input Voltage	–0.5 to +7.0	V	
V _{OUT}	DC Output Voltage		–0.5 to V _{CC} +0.5	V
I _{IK}	DC Input Diode Current		-50	mA
I _{OK}	DC Output Diode Current		-50	mA
I _{OUT}	DC Output Sink Current		±50	mA
I _{CC}	DC Supply Current per Supply Pin	±100	mA	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance	SOT-353 (Note 1) SOT-553	350 496	°C/W
PD	Power Dissipation in Still Air at 85°C	SOT-353 SOT-553	186 135	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD	ESD Classification	Human Body Model (Note 2) Machine Model (Note 3)	4000 400	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect Mecommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommendation of the Recommendation of

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Max	Units
V _{CC}	DC Supply Voltage			5.5	V
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage		0	5.5	V
T _A	Operating Temperature Range		-55	+125	°C
t _r , t _f	Input Rise and Fall Time	$\begin{array}{l} V_{CC} = 3.0 \ V \pm 0.3 \ V \\ V_{CC} = 5.0 \ V \pm 0.5 \ V \end{array}$	0 0	100 20	ns/V

			V _{cc}	T,	A = 25°	С	–55°C ≤ T	_A ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
V _{IH}	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75 V _{CC} 0.7 V _{CC}			0.75 V _{CC} 0.7 V _{CC}		V
V _{IL}	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V _{CC} 0.3 V _{CC}		0.25 V _{CC} 0.3 V _{CC}	V
V _{OH}	High-Level Output Voltage	I _{OH} = 100 μA	1.65 to 5.5	V _{CC} - 0.1	V _{CC}		V _{CC} - 0.1		V
	$V_{IN} = V_{IL} \text{ or } V_{IH}$	I _{OH} = -3 mA	1.65	1.29	1.52		1.29		
		I _{OH} = -8 mA	2.3	1.9	2.1		1.9		
		I _{OH} = -12 mA	2.7	2.2	2.4		2.2		
		I _{OH} = -16 mA	3.0	2.4	2.7		2.4		
		I _{OH} = -24 mA	3.0	2.3	2.5		2.3		
		I _{OH} = -32 mA	4.5	3.8	4.0		3.8		
V _{OL}	Low-Level Output Voltage	l _{OL} = 100 μA	1.65 to 5.5			0.1		0.1	V
	$V_{IN} = V_{IH} \text{ or } V_{OH}$	I _{OL} = 3 mA	1.65		0.08	0.24		0.24	
		I _{OL} = 8 mA	2.3		0.20	0.3		0.3	
		l _{OL} = 12 mA	2.7		0.22	0.4		0.4	
		l _{OL} = 16 mA	3.0		0.28	0.4		0.4	
		I _{OL} = 24 mA	3.0		0.38	0.55		0.55	
		I _{OL} = 32 mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	$V_{IN} = 5.5 \text{ V or GND}$	0 to 5.5			±0.1		±1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	0			1		10	μΑ
I _{CC}	Quiescent Supply Current	V _{IN} = 5.5 V or GND	5.5			1		10	μA

DC ELECTRICAL CHARACTERISTICS

AC ELECTRICAL CHARACTERISTICS t_R = t_F = 3.0 ns

			V _{cc}	T _A = 25°C		–55°C ≤ T _A ≤ 125°C			
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Мах	Units
t _{PLH}	Propagation Delay	R_L = 1 M Ω , C_L = 15 pF	1.65	2.0	5.5	12.0	2.0	12.7	ns
t _{PHL}	(Figure 3 and 4)	R_L = 1 M Ω , C_L = 15 pF	1.8	2.0	4.6	10	2.0	10.5	
		R_L = 1 M Ω , C_L = 15 pF	$\textbf{2.5}\pm\textbf{0.2}$	0.8	3.0	7	0.8	7.5	
		R_L = 1 M Ω , C_L = 15 pF	$\textbf{3.3}\pm\textbf{0.3}$	0.5	2.6	4.7	0.5	5.0	
		$\text{R}_{\text{L}} = 500 \ \Omega, \ \text{C}_{\text{L}} = 50 \ \text{pF}$		1.5	3.0	5.2	1.5	5.5	
		R_L = 1 M Ω , C_L = 15 pF	5.0 ± 0.5	0.5	2.2	4.1	0.5	4.4	
		$R_{L} = 500 \ \Omega, \ C_{L} = 50 \ pF$		0.8	2.4	4.5	0.8	4.8	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Units
C _{IN}	Input Capacitance	V_{CC} = 5.5 V, V_I = 0 V or V_{CC}	>4	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	25	pF
	(Note 4)	10 MHz, V_{CC} = 5.5 V, V_{I} = 0 V or V_{CC}	30	

4. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

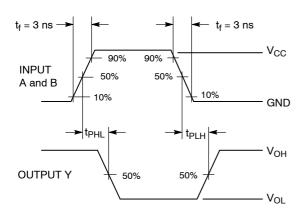
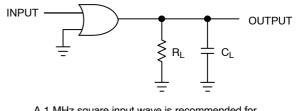
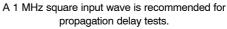


Figure 3. Switching Waveform







ORDERING INFORMATION

Device Order Number	g_	
NL17SZ32DFT2G	SC-88A/SC-70-5/SOT-353 (Pb-Free)	3000 / Tape & Reel
NLV17SZ32DFT2G*	SC-88A/SC-70-5/SOT-353 (Pb-Free)	3000 / Tape & Reel
NL17SZ32XV5T2G	SOT-553 (Pb-Free)	4000 / Tape & Reel

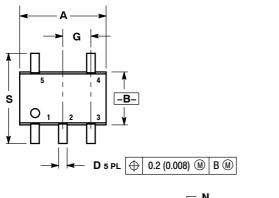
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

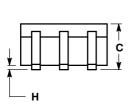
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

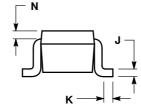
NL17SZ32

PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353) DF SUFFIX CASE 419A-02 ISSUE K







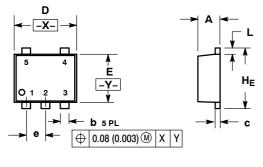
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
C	0.031	0.043	0.80	1.10	
D	0.004 0.012 0.	0.10	0.30		
G	0.026	BSC	0.65	BSC	
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
Κ	0.004 0.0		0.10	0.30	
Ν	0.008	REF	0.20	REF	
S	0.079	0.087	2.00	2.20	

NL17SZ32

PACKAGE DIMENSIONS

SOT-553 **XV5 SUFFIX** CASE 463B **ISSUE B**



CATHODE

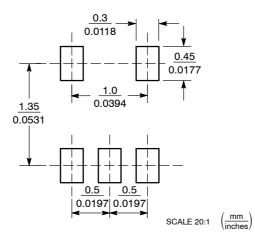


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2 З.
- CONTROLLING DIMENSION: MILLIMETERS MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS				INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.13	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.063	0.067
Е	1.10	1.20	1.30	0.043	0.047	0.051
е		0.50 BSC		0.020 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.063	0.067

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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